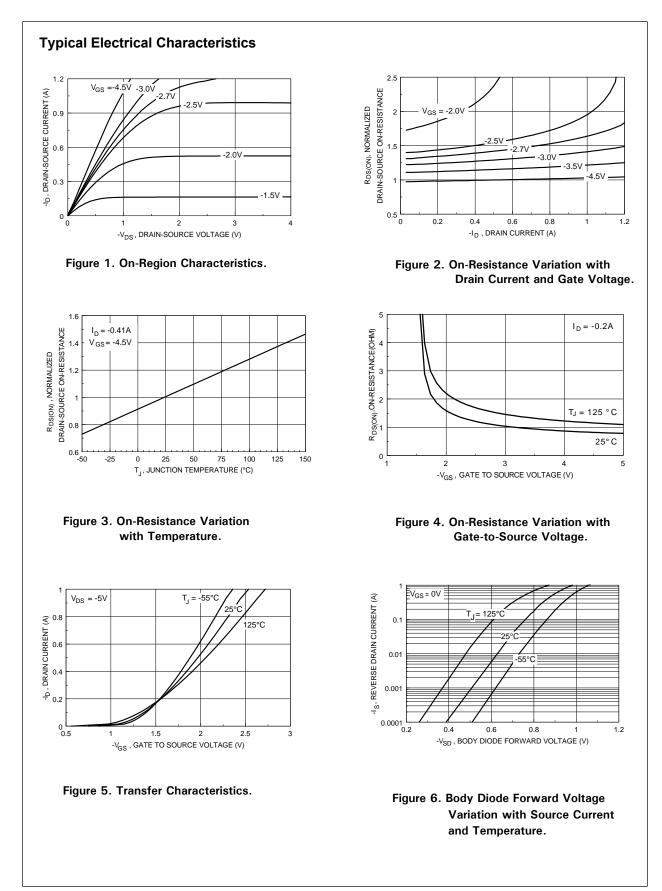


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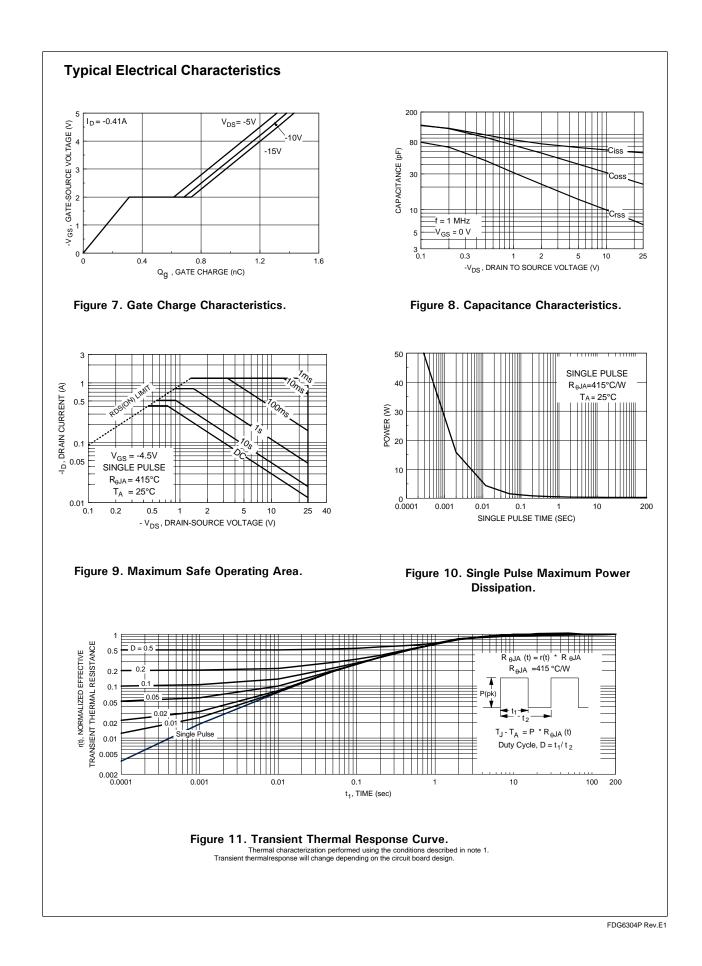
Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAR	ACTERISTICS					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$	-25			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = -250 µA, Referenced to 25°C		-22		mV /°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -20 V, V_{GS} = 0 V$			-1	μA
		$T_{J} = 55^{\circ}C$			-10	μA
I _{GSS}	Gate - Body Leakage Current	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
	CTERISTICS (Note 2)	•				
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.65	-0.82	-1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp.Coefficient	$I_{\rm D}$ = -250 µA, Referenced to 25°C		2		mV /⁰C
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} = -4.5 V, I _D = -0.41 A		0.85	1.1	Ω
		T _J =125°C		1.2	1.9	
		V _{GS} = -2.7 V, I _D = -0.25 A		1.15	1.5	
I _{D(ON)}	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-1.5			Α
9 _{FS}	Forward Transconductance	$V_{\rm DS} = -5 \text{ V}, \ \text{I}_{\rm D} = -0.41 \text{ A}$		0.9		S
DYNAMIC C	HARACTERISTICS					
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		62		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		34		pF
C _{rss}	Reverse Transfer Capacitance			10		pF
SWITCHING	CHARACTERISTICS (Note 2)					
t _{D(on)}	Turn - On Delay Time	$V_{DD} = -5 V, I_{D} = -0.5 A,$		7	15	ns
t,	Turn - On Rise Time	$V_{GS} = -4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		8	16	ns
t _{D(off)}	Turn - Off Delay Time			55	80	ns
t _r	Turn - Off Fall Time			35	60	ns
Q _g	Total Gate Charge	$V_{DS} = -5 V, I_{D} = -0.41 A,$		1.1	1.5	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		0.31		nC
Q_{gd}	Gate-Drain Charge			0.29		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MAXIM	UM RATINGS				
I _s	Maximum Continuous Source Current				-0.25	А
V _{SD}	Drain-Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_{S} = -0.25 \text{ A}_{(Note 2)}$			-0.85	-1.2	V

Notes:

1. R_{pik} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{pik} is guaranteed by design while R_{hch} is determined by the user's board design. $R_{hch} = 415^{\circ}$ C/W on minimum pad mounting on FR-4 board in still air. 2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.



FDG6304P Rev.E1



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